

### DESCRIPTION

The IS281 series optocoupler consists of an infrared emitting diode optically coupled to an NPN silicon photo transistor.

This device belongs to Isocom Compact Range of Optocouplers.

### FEATURES

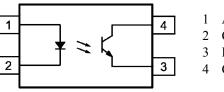
- Half Pitch 1.27mm
- High AC Isolation voltage 3750V<sub>RMS</sub>
- CTR Selections Available
- Wide Operating Temperature Range -55°C to 110°C
- Pb Free and RoHS Compliant
- UL Approval E91231, Model "THP"

### APPLICATIONS

- Switching Mode Power Supply
- Industrial System Controllers
- Measuring Instruments
- Signal Transmission between Systems of Different Potentials and Impedances

### **ORDER INFORMATION**

 Available in Tape and Reel with 1000pcs per reel



- 1 Anode 2 Cathode
- 2 Califord 3 Emitter
- 5 Ellittei
- 4 Collector

### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^{\circ}C$ )

Stresses exceeding the absolute maximum ratings can cause permanent damage to the device. Exposure to absolute maximum ratings for long periods of time can adversely affect reliability.

#### Input

Forward Current	50mA
Reverse Voltage	6V
Power dissipation	70mW

#### Output

Collector to Emitter Voltage BV <sub>CEO</sub>	80V
Emitter to Collector Voltage BV <sub>ECO</sub>	7V
Collector Current	50mA
Power Dissipation	150mW

#### **Total Package**

Isolation Voltage	$3750V_{\text{RMS}}$
Total Power Dissipation	200mW
Operating Temperature	-55 to 110 °C
Storage Temperature	-55 to 150 °C
Lead Soldering Temperature (10s)	260°C

#### ISOCOM COMPONENTS 2004 LTD

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## ELECTRICAL CHARACTERISTICS (T<sub>A</sub> = 25°C unless otherwise specified)

#### INPUT

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Forward Voltage	$V_{\rm F}$	$I_F = 20 m A$		1.2	1.4	V
Reverse Current	I <sub>R</sub>	$V_R = 4V$			10	μA
Terminal Capacitance	C <sub>IN</sub>	V = 0V, f = 1KHz		30	250	pF

### OUTPUT

Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	$I_{\rm C} = 0.1 {\rm mA},  I_{\rm F} = 0 {\rm mA}$	80			V
Emitter-Collector Breakdown Voltage	BV <sub>ECO</sub>	$I_{E} = 0.1 \text{mA}, I_{F} = 0 \text{mA}$	7			V
Collector-Emitter Dark Current	I <sub>CEO</sub>	$V_{CE} = 20V, I_F = 0mA$			100	nA



## **ELECTRICAL CHARACTERISTICS** ( $T_A = 25^{\circ}C$ unless otherwise specified)

#### COUPLED

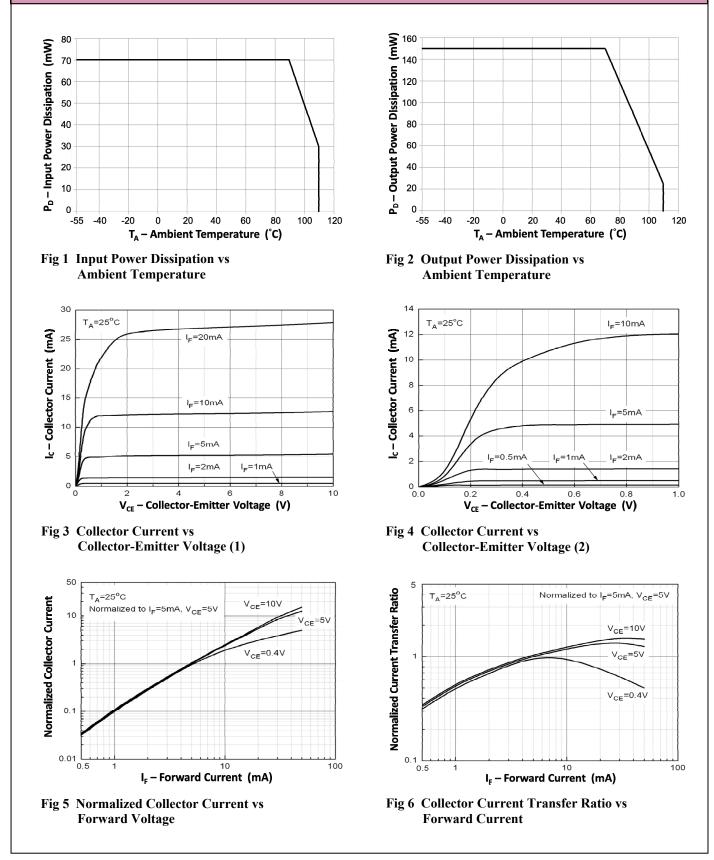
Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Current transfer ratio	CTR	$I_F = 5mA$ , $V_{CE} = 5V$				%
		IS281	50		600	
		IS281A	80		160	
		IS281B	130		260	
		IS281C	200		400	
		IS281D	300		600	
		IS281E	100		200	
		IS281F	150		300	
		IS281GB	100		600	
		$I_F = 10mA, V_{CE} = 5V$				
		IS281H	40		80	
		IS281I	63		125	
		IS281J	100		200	
		IS281K	160		320	
		IS281GR	100		300	
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	$I_{\rm F} = 10 {\rm mA}, I_{\rm C} = 1 {\rm mA}$		0.1	0.2	V
Floating Capacitance	$C_{f}$	$V_F = 0V, f = 1MHz$		0.3		pF
Output Rise Time	t <sub>r</sub>	$V_{CE} = 2V, Ic = 2mA, R_{L} = 100\Omega$		6	18	μs
Output Fall Time	t <sub>f</sub>	$V_{CE} = 2V, Ic = 2mA, R_L = 100\Omega$		6	18	μs

### ISOLATION

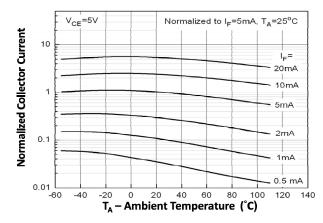
Parameter	Symbol	Test Condition	Min	Тур.	Max	Unit
Isolation Voltage	V <sub>ISO</sub>	R.H. = 40% to 60%, t = 1 min Note 1	3750			V <sub>RMS</sub>
Input - Output Resistance	R <sub>I-O</sub>	$V_{I-O} = 500VDC$ R.H. = 40% to 60% Note 1	5x10 <sup>10</sup>			Ω

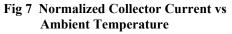
Note 1 : Measured with input leads shorted together and output leads shorted together.











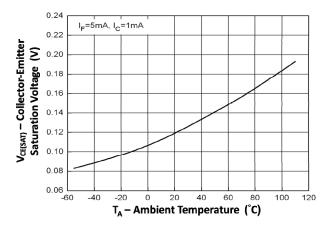
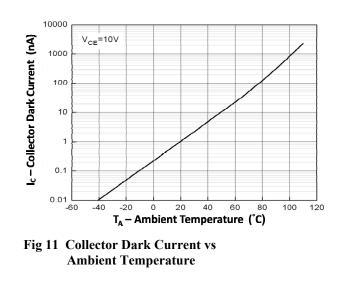
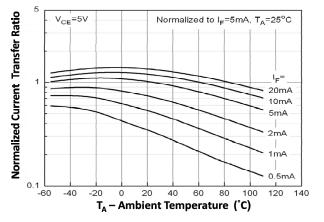
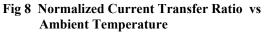


Fig 9 Collector-Emitter Voltage vs Ambient Temperature







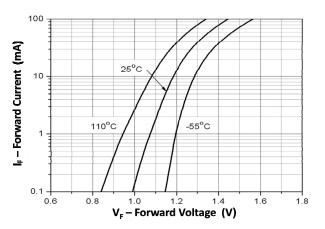
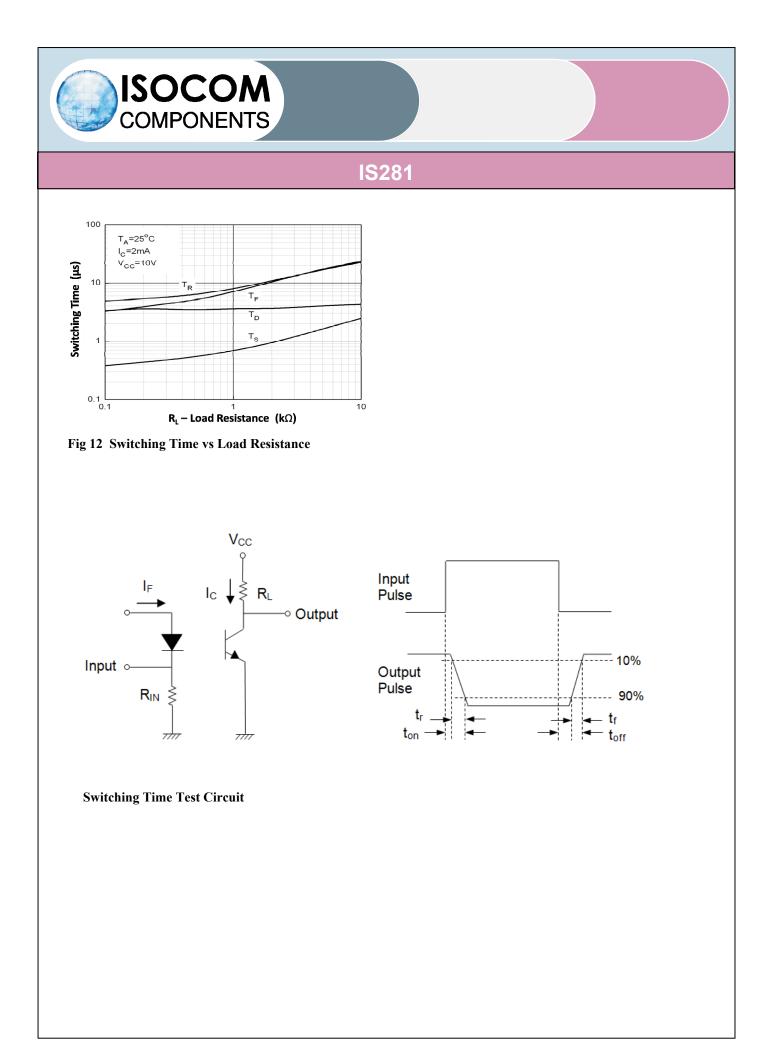


Fig 10 Forward Current vs Forward Voltage





#### **ORDER INFORMATION**

After PN	PN	Description	Packing quantity
None	IS281	Surface Mount Tape & Reel	1000 pcs per reel
Any CTR Grade	IS281A, IS281B, IS281C, IS281D, IS281E, IS281F, IS281H, IS281I, IS281J, IS281K, IS281GR, IS281GB	Surface Mount Tape & Reel	1000 pcs per reel

#### **DEVICE MARKING**



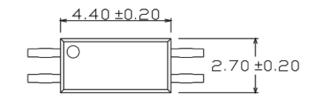
	THP	denotes Device Part Number where "	" denotes CTR Grade
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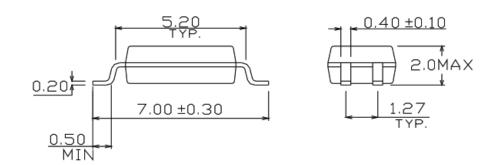
- I denotes Isocom
- Y denotes 1 digit Year code
- WW denotes 2 digit Week code

Note :	Device	<b>Optional Marking</b>
	IS281	THP1
	IS281B	THP3
	IS281F	THP10

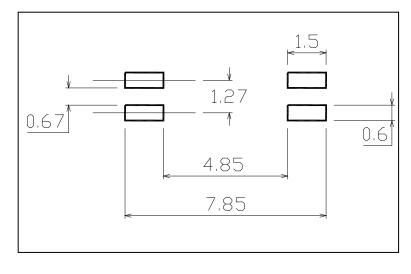


### PACKAGE DIMENSIONS (mm)



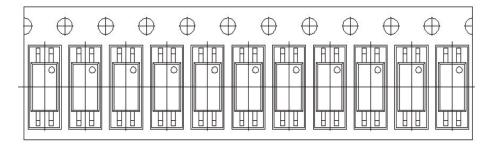


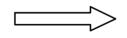
### **RECOMMENDED SOLDER PAD LAYOUT (mm)**



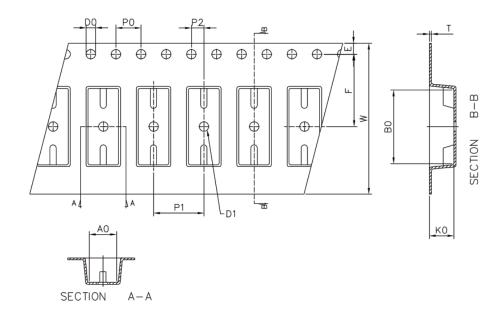


### Tape and Reel Packaging





Direction of feed from reel

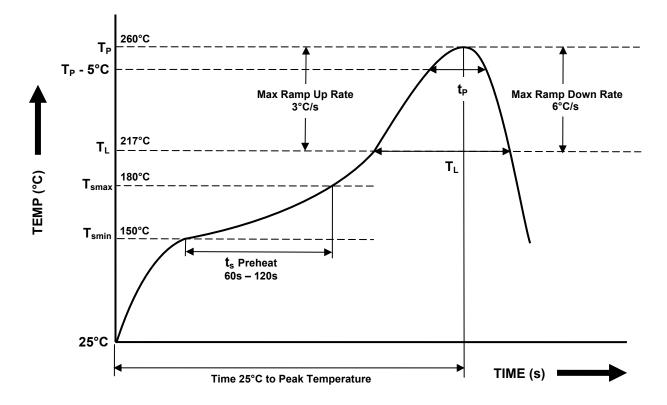


Dimension No.	A0	В0	D0	D1	E	F
Dimension( mm)	3.00±0.10	7.45±0.10	1.50+0.1/-0	1.50±0.10	1.75±0.10	5.5±0.10
Dimension No.	P0	P1	P2	t	W	K0
Dimension (mm)	4.00±0.15	4.00±0.10	2.00±0.10	0.30±0.05	12.1±0.2	2.45±0.1



#### IR REFLOW SOLDERING TEMPERATURE PROFILE One Time Reflow Soldering is Recommended.

Do not immerse device body in solder paste.



Profile Details	Conditions
Preheat - Min Temperature (T <sub>SMIN</sub> ) - Max Temperature (T <sub>SMAX</sub> ) - Time T <sub>SMIN</sub> to T <sub>SMAX</sub> (t <sub>s</sub> )	150°C 180°C 60s - 120s
	260°C 217°C 20s 60s 3°C/s max 3 - 6°C/s
Average Ramp Up Rate (T <sub>smax</sub> to T <sub>P</sub> )	3°C/s max
Time 25°C to Peak Temperature	8 minutes max



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